# **Thyristor Surge Suppressors (TSS) Data Sheet**

## **Description**

DO-214AC Thyristor solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

P Series devices are used to enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, UL 60950, and TIA-968 (formerly known as FCC Part 68).



#### **Features**

Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigue
- Have low capacitance, making them ideal for high-speed transmission equipment
- Meets MSL level 1, per J-STD-020
- Safety certification: UL: E244458

#### **Electrical Parameters**

Parameter	Definition				
$V_{DRM}$	Peak Off-state Voltage – maximum voltage that can be applied while maintaining off state				
Vs	Switching Voltage – maximum voltage prior to switching to on state				
V <sub>T</sub>	On-state Voltage – maximum voltage measured at rated on-state current				
I <sub>DRM</sub>	Leakage Current – maximum peak off-state current measured at V <sub>DRM</sub>				
Is	Switching Current – maximum current required to switch to on state				
I <sub>T</sub>	On-state Current – maximum rated continuous on-state current				
I <sub>H</sub>	Holding Current – minimum current required to maintain on state				
Co	Off-state Capacitance – typical capacitance measured in off state				
I <sub>PP</sub>	Peak Pulse Current – maximum rated peak impulse current				
I <sub>TSM</sub>	Peak One-cycle Surge Current – maximum rated one-cycle AC current				
di/dt	Rate of Rise of Current – maximum rated value of the acceptable rate of rise in current over time				

# **Electrical Characteristics**

Part Number	V <sub>DRM</sub> (V)	V <sub>S</sub> (V)	V <sub>T</sub> (V)	I <sub>DRM</sub> (μΑ)	I <sub>S</sub> (mA)	I <sub>T</sub> (A)	I <sub>H</sub> (mA)	C <sub>o</sub> (pF)	Marking
P0080TA	6	25	4	5	800	2.2	50	50	P008A
P0300TA	25	40	4	5	800	2.2	50	70	P03A
P0640TA	58	77	4	5	800	2.2	150	50	P06A
P0720TA	65	88	4	5	800	2.2	150	50	P07A
P0900TA	75	98	4	5	800	2.2	150	45	P09A
P1100TA	90	130	4	5	800	2.2	150	45	P11A
P1300TA	120	160	4	5	800	2.2	150	45	P13A
P1500TA	140	180	4	5	800	2.2	150	40	P15A
P1800TA	170	220	4	5	800	2.2	150	40	P18A
P2300TA	190	260	4	5	800	2.2	150	35	P23A
P2600TA	220	300	4	5	800	2.2	150	35	P26A
P3100TA	275	350	4	5	800	2.2	150	30	P31A
P3500TA	320	400	4	5	800	2.2	150	30	P35A

## Notes:

- All measurements are made at an ambient temperature of 25  $^\circ$ C. I<sub>PP</sub> applies to -40  $^\circ$ C through +85  $^\circ$ C temperature range.
- Off-state capacitance( $C_0$ ) is measured at 1 MHz with a 2V bias and is typical value.
- For surge ratings, see table below.

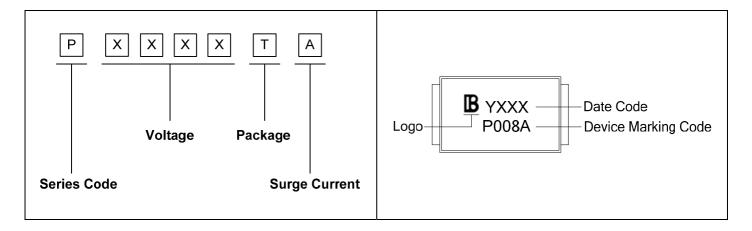
# **Surge Ratings**

Series	I <sub>PP</sub> 2×10µs (A)	I <sub>PP</sub> 8×20µs (A)	I <sub>PP</sub> 10×160μs (A)	I <sub>PP</sub> 10×560μs (A)	I <sub>PP</sub> 10×1000μs (A)	I <sub>TSM</sub> 60Hz (A)	di/dt (A/µs)
Α	150	150	90	50	45	20	500

## **Thermal Considerations**

Package DO-214AC/SMA	Symbol	Parameter	Value	Unit
	$T_J$	Operating Junction Temperature	-40 to +150	$^{\circ}$
	Ts	Storage Temperature Range	-40 to +150	$^{\circ}$
	$R_{\theta JA}$	Junction to Ambient on printed circuit	120	°C/W

# **Part Number Code and Marking**



## **Characteristics Curves**

Figure 1. V-I Characteristics

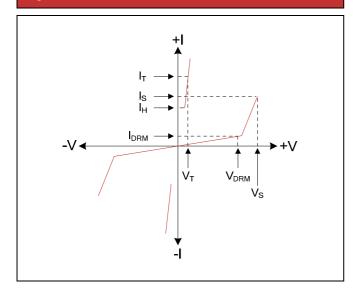


Figure 3. Normalized Vs Change versus Junction Temperature

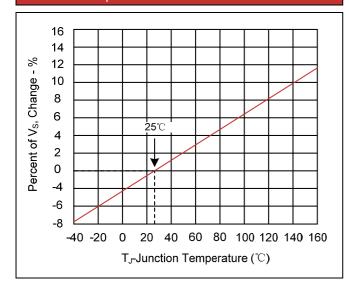


Figure 2. tr × td Pulse Wave-form

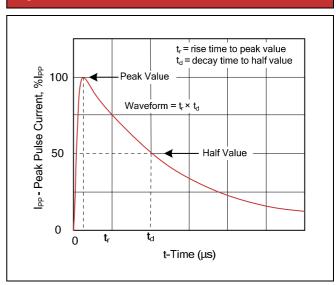
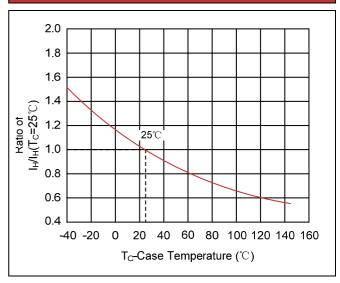
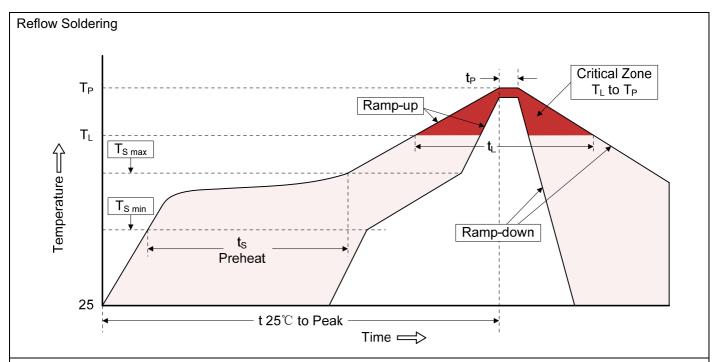


Figure 4. Normalized DC Holding Current versus CaseTemperature



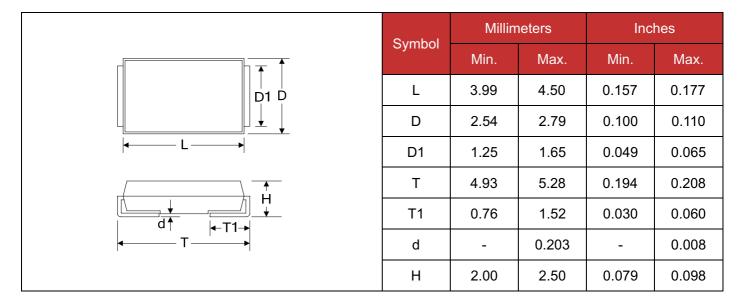
# **Recommended Soldering Conditions**



## **Recommended Conditions**

Profile Feature	Pb-Free Assembly
Average ramp-up rate (T <sub>L</sub> to T <sub>P</sub> )	3°C/second max.
Preheat -Temperature Min (T <sub>S min</sub> ) -Temperature Max (T <sub>S max</sub> ) -Time (min to max) (t <sub>S</sub> )	150℃ 200℃ 60-180 seconds
T <sub>S max</sub> to T <sub>L</sub> -Ramp-up Rate	3°C/second max.
Time maintained above: -Temperature $(T_L)$ -Time $(t_L)$	217℃ 60-150 seconds
Peak Temperature (T <sub>P</sub> )	260℃
Time within 5°C of actual Peak Temperature (t <sub>P</sub> )	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25℃ to Peak Temperature	8 minutes max.

# **Dimensions (SMA/DO-214AC)**



# **Packaging**

